

Supplementary Material for

Origin of Ligand-Driven Selectivity in Alkyne Semihydrogenation over Silica-Supported Copper Nanoparticles

5 *Nicolas Kaeffer,^{a,‡} Kim Larmier,^{a,b,‡} Alexey Fedorov,^{a,c} Christophe Copéret^{a,*}*

a) ETH Zürich, Department of Chemistry and Applied Biosciences, Vladimir-Prelog-Weg 1-5, CH-8093, Zürich, Switzerland.

b) Current address: IFP Energies nouvelles, Rond-Point de l'échangeur de Solaize, BP3, 69360 Solaize, France.

10 c) Current address: ETH Zürich, Department of Mechanical and Process Engineering, Leonhardstrasse 21, CH-8092 Zürich, Switzerland.

* ccoperet@inorg.chem.ethz.ch

Table of Contents

	GAS ADSORPTION ISOTHERMS	2
15	GAS CHROMATOGRAPHY DATA	4
	DETERMINATION OF PARTIAL ORDERS	5
	EXPRESSIONS OF ADSORPTION CONSTANTS	8
	SUBSTRATE ADSORPTION ISOTHERMS	9
	ADSORBATE GEOMETRIES AND DENSITY MAPS	10
20	KINETIC DATA AND MODELLING	12
	REFERENCES	14

Gas adsorption isotherms

25

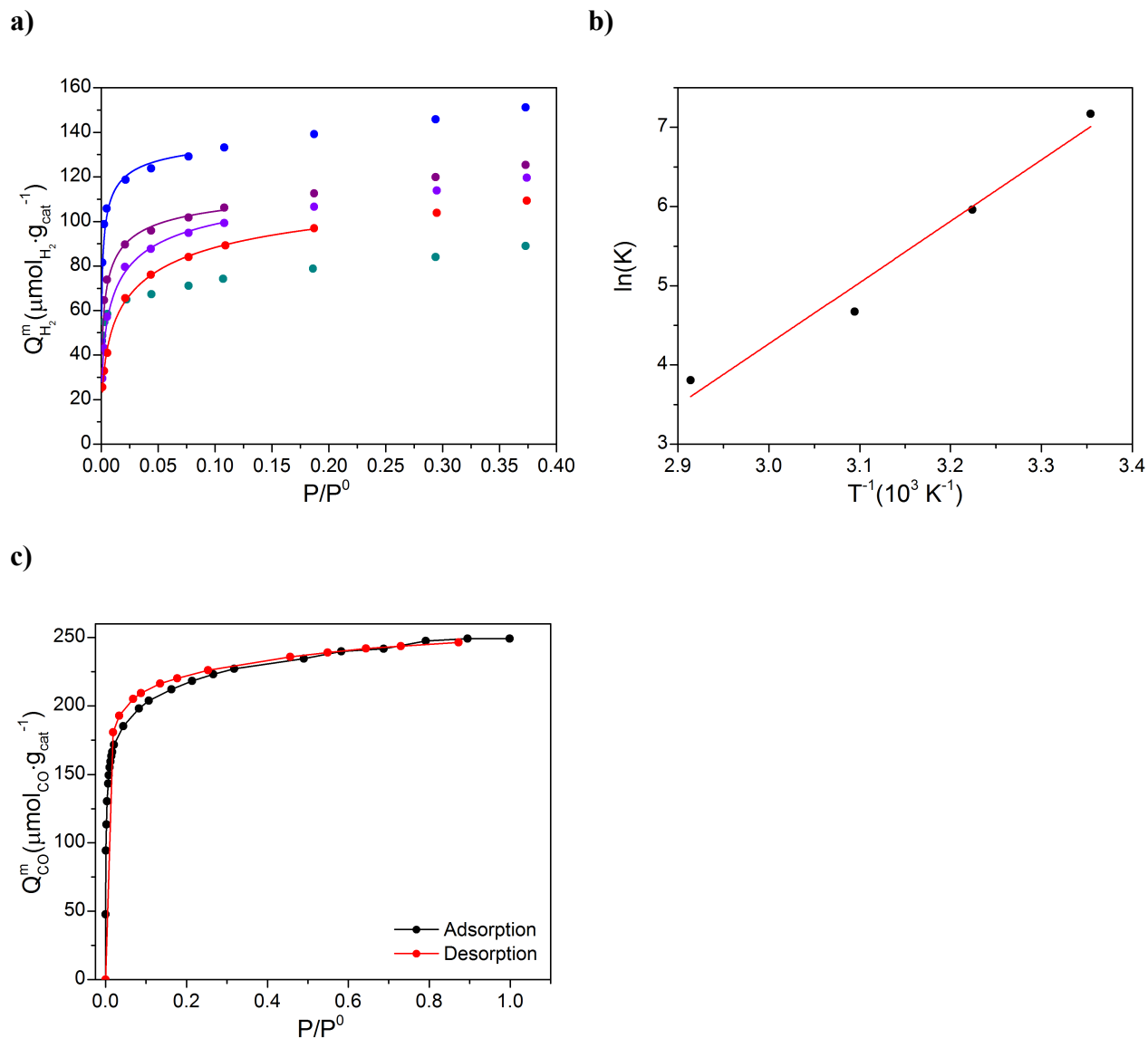


Figure S1. a) H₂ adsorption isotherms on Cu/SiO₂ (dots) at 5 (cyan), 25 (blue), 37 (purple), 50 (violet) and 70 (red) °C with Langmuir dissociative adsorption isotherm fits (lines); b) $\ln(K_{H_2})$ vs T^{-1} plot (dots) and associated linear fit (line); c) CO adsorption (black) and desorption (red) isotherms on Cu/SiO₂ at 25 °C.

H₂ chemisorption curves were fitted with a Langmuir dissociative adsorption isotherm following:

$$Q_{H_2}(P) = Q_{H_2}^{max} \cdot \frac{\sqrt{K_{H_2} \frac{P}{P^0}}}{1 + \sqrt{K_{H_2} \frac{P}{P^0}}} \quad \text{Equation S1}$$

where Q_{H_2} , $Q_{H_2}^{max}$ are coverage and maximal coverage in H_2 , respectively, while P and P^0 are partial and standard (1 bar) pressure in H_2 and K_{H_2} is the adsorption equilibrium constant for H_2 .

30 Fitting H_2 isotherms allowed estimating the maximal surface coverage in H_2 as:

$$Q_{H_2}^{max} = 130 \mu mol_{H_2} \cdot g_{cat}^{-1}$$

35 This figure is in agreement with the maximal coverage found by CO chemisorption (ca. $240 \mu mol_{CO} \cdot g_{cat}^{-1}$), taking into account that H_2 occupies ca. two Cu sites,^[1] whereas CO occupies one Cu site.

We estimated the standard adsorption enthalpy of H_2 on **Cu/SiO₂** using Van't Hoff equation:

$$\ln(K_{H_2}) = -\frac{\Delta H_{ads}^0}{R} \cdot T^{-1} + \frac{\Delta S_{ads}^0}{R} \quad \text{Equation S2}$$

40

from which we could recover by the linear fitting of data presented in **Figure S1b**:

$$\Delta H_{ads}^0 = -64 \text{ kJ} \cdot \text{mol}^{-1}$$

45

Gas chromatography data**Table S1.** Molar ratios (%) in hydrogenation products from GC analysis of final mixtures (16.3 h).

Ligand	L/S	S	(Z)-S_{2H}	(E)-S_{2H}	S_{4H}
None	–	0	0	0	100
None	–	0	0	0	100
PCy ₃	1:50	0	51	12	37
PCy ₃	1:50	0	55	12	34
PCy ₃	1:100	0	46	10	44
PCy ₃	1:100	0	51	12	37
IMes	1:50	0	88	2	10

Determination of partial orders

55 The partial orders with respect to the concentration of alkyne [S], the concentration of catalyst [cat] and the pressure of hydrogen P_{H_2} have been determined for the first part of the curves, corresponding mainly to the hydrogenation of S to S_{2H}. We assumed that the rate expression is of the form

Equations S3
$$r = k[S]^\alpha[\text{cat}]^\beta P_{H_2}^\gamma$$

60 We measured the rates under different sets of experimental conditions by systematic variations of only one of the [S], [cat] and P_{H_2} parameters. The two other parameters are set to the reference values used within the manuscript ([S] = 0.30 mol·L⁻¹, [cat] = 5.00 g_{cat}·L⁻¹ and P_{H_2} = 10 bar). The obtained curves are linear in the first section, and the rates r are measured as the slope of these H₂ consumption curves. We then draw logarithmic plots of the experimental rates as a function of the varied parameter and obtain the respective partial order as the slope of the corresponding linear fit.

65 Partial order in [S]

Table S2. Experimental rates for determination of partial orders in [S]

Entry	[S] (mol·L ⁻¹)	r (mol·L ⁻¹ ·h ⁻¹)
1	0.20	0.0306
2	0.15	0.0330
3	0.30	0.0315

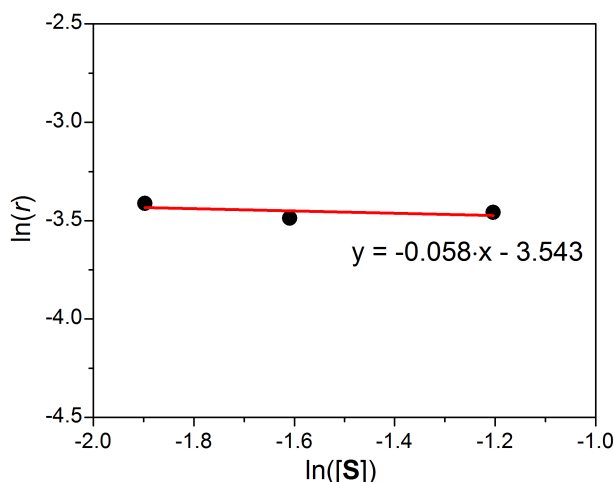


Figure S2. Order plot of the initial hydrogenation rate of S (r) with respect to the substrate concentration [S].

70 The rate is found nearly independent on the substrate concentration and we determine from the plot $\alpha = -0.058$, very close to a zero-order dependence.

Partial order in [cat]

Table S3. Experimental rates for determination of partial order in [cat]

Entry	[cat] ($\text{g}_{\text{cat}}\cdot\text{L}^{-1}$)	r ($\text{mol}\cdot\text{L}^{-1}\cdot\text{h}^{-1}$)
1	2.50	0.0139
2	3.75	0.0225
3	5.00	0.0320
4	6.25	0.0402

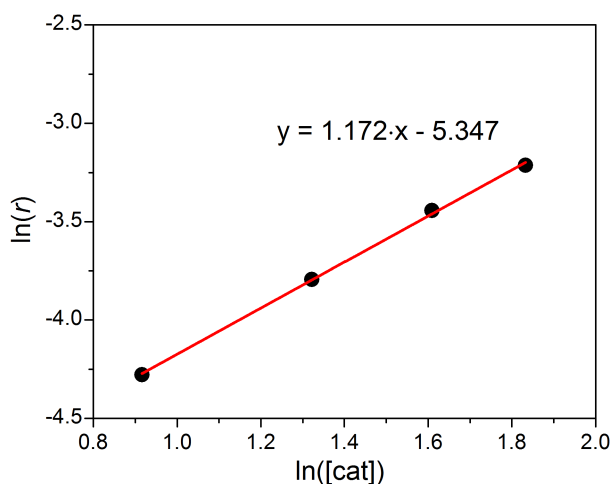


Figure S3. Order plot of the initial hydrogenation rate of S (r) with respect to the catalyst concentration [cat].

75

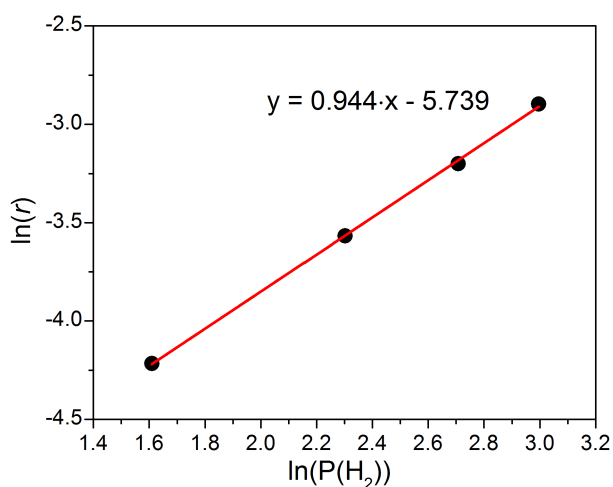
The rate is found to be linearly dependent on the catalyst concentration and we determine from the plot $\beta = 1.172$, very close to a first-order dependence.

80

Partial order in P_{H_2} **Table S4.** Experimental rates for determination of partial orders in P_{H_2}

Entry	P_{H_2} (bar)	r (mol·L ⁻¹ ·h ⁻¹)
1	5	0.0148
2	10	0.0282
3	15	0.0408
4	20	0.0552

85

**Figure S4.** Order plot of the initial hydrogenation rate of **S** (r) with respect to the pressure of H_2 concentration P_{H_2} .

The rate is found to be linearly dependent on the catalyst concentration and we determine from the plot $\gamma = 0.944$, very close to a first-order dependence.

90 **Expressions of adsorption constants**

95 Adsorption constants K_i in the rate equations (**Equations 4** and **5**) can be expressed within a Langmuir-Hinshelwood formalism^[2, 3] considering here one type of active Cu sites (*) and the equilibria of **S**, **S_{2H}**, **S_{4H}** and a ligand **L** in solution with their respective **S***, **S_{2H}***, **S_{4H}*** and **L*** adsorbates on these sites (**Scheme 1c**). This formalism leads to **Equations S4**, where $[i]$ are concentrations in solution, $[i^*]$ and $[*]$ are concentrations of surface species for adsorbates and empty active sites, respectively, and C^0 is the standard concentration ($C^0 = 1 \text{ mol} \cdot \text{L}^{-1}$). From **Equations S4**, we derive **Equations S5** where we express the fraction θ_i of surface species $[i^*]$ relative to the total active site concentration $[*]_{tot}$ as a function of the concentrations of species in the liquid-phase $[i]$, the adsorption constants K_i and the denominator Γ (**Equation 6**).

100

$$\text{Equations S4} \quad \text{(a)} \quad K_A = \frac{[\mathbf{S}^*]C^0}{[\mathbf{S}][*]} \quad \text{(b)} \quad K_B = \frac{[\mathbf{S}_{2H}^*]C^0}{[\mathbf{S}_{2H}][*]} \quad \text{(c)} \quad K_C = \frac{[\mathbf{S}_{4H}^*]C^0}{[\mathbf{S}_{4H}][*]} \quad \text{(d)} \quad K_L = \frac{[\mathbf{L}^*]C^0}{[\mathbf{L}][*]}$$

$$\text{Equations S5} \quad \text{(a)} \quad \theta_A = \frac{[\mathbf{S}^*]}{[*]_{tot}} = \frac{K_A[\mathbf{S}]}{\Gamma C^0} \quad \text{(b)} \quad \theta_B = \frac{[\mathbf{S}_{2H}^*]}{[*]_{tot}} = \frac{K_B[\mathbf{S}_{2H}]}{\Gamma C^0} \quad \text{(c)} \quad \theta_C = \frac{[\mathbf{S}_{4H}^*]}{[*]_{tot}} = \frac{K_C[\mathbf{S}_{4H}]}{\Gamma C^0}$$

$$\text{(d)} \quad \theta_* = \frac{[*]}{[*]_{tot}} = \frac{1}{\Gamma} \quad \text{(e)} \quad \theta_L = \frac{[\mathbf{L}^*]}{[*]_{tot}} = \frac{K_L[\mathbf{L}]}{\Gamma C^0}$$

Substrate adsorption isotherms

105

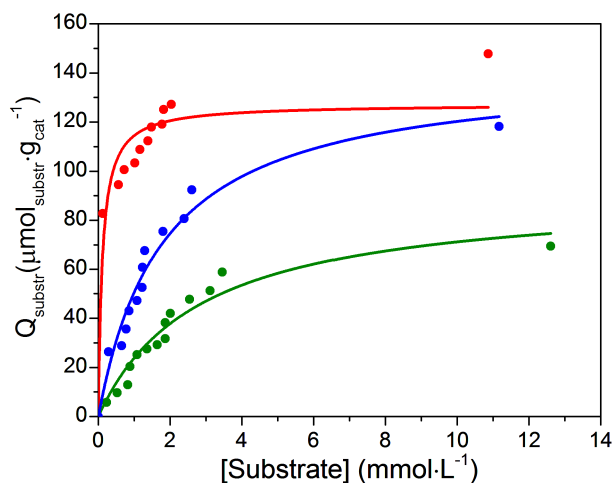


Figure S5. S (red), (E)-S_{2H} (blue) and S_{4H} (green) adsorption isotherms on Cu/SiO₂ at 40 °C (dots) and associated Langmuir associative adsorption isotherms (solid lines).

Substrate chemisorption curves were fitted with a Langmuir associative adsorption isotherm of the formula:

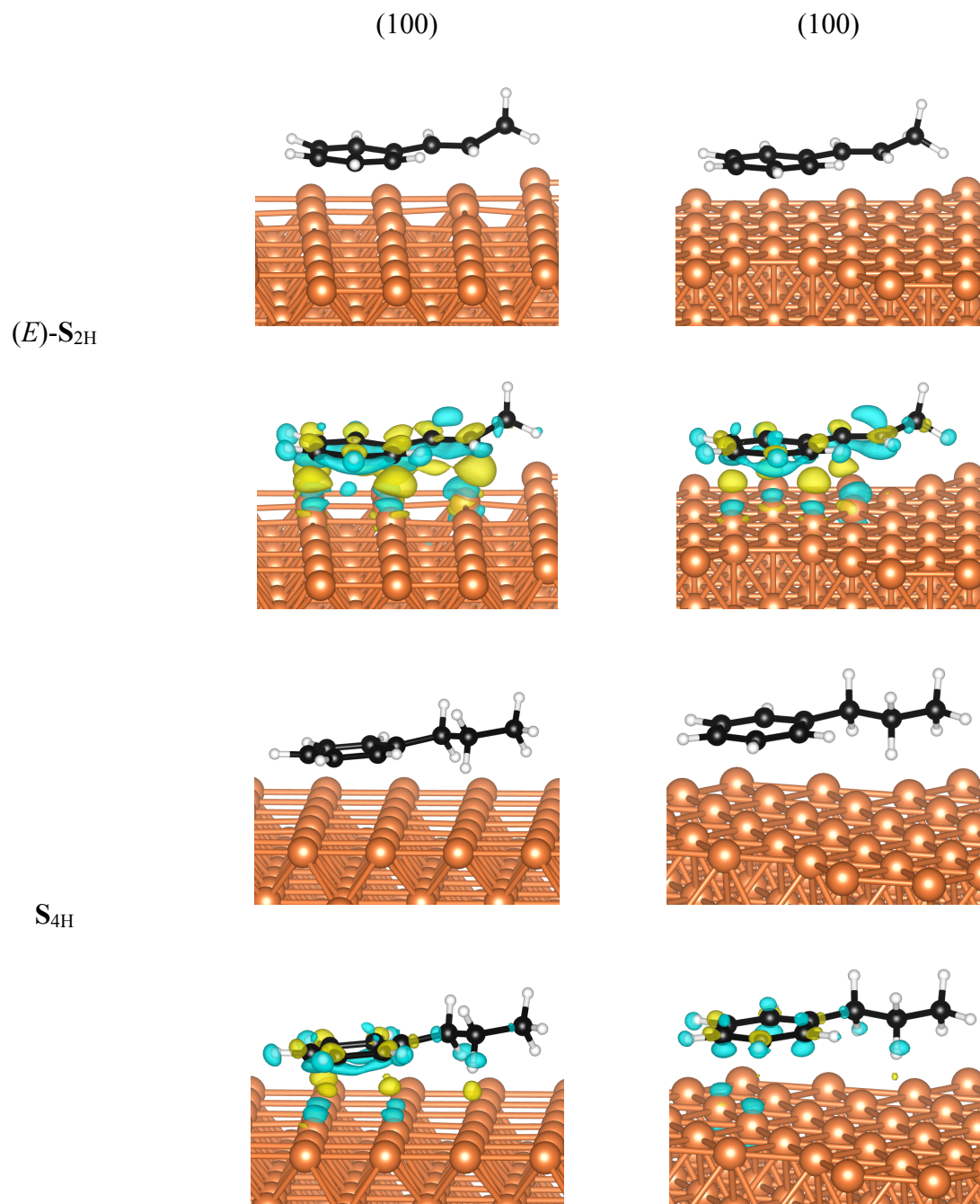
Equations S6

$$Q_i([i]) = Q_i^{max} \cdot \frac{K_i \frac{[i]}{C^0}}{1 + K_i \frac{[i]}{C^0}}$$

110 where Q_i , Q_i^{max} are respectively coverage at equilibrium and maximal coverage in substrate i , $[i]$ and C^0 respectively concentration and standard concentration (1 mol·L⁻¹) in i substrate and K_i the adsorption equilibrium constant for i substrate.

Adsorbate geometries and density maps

115



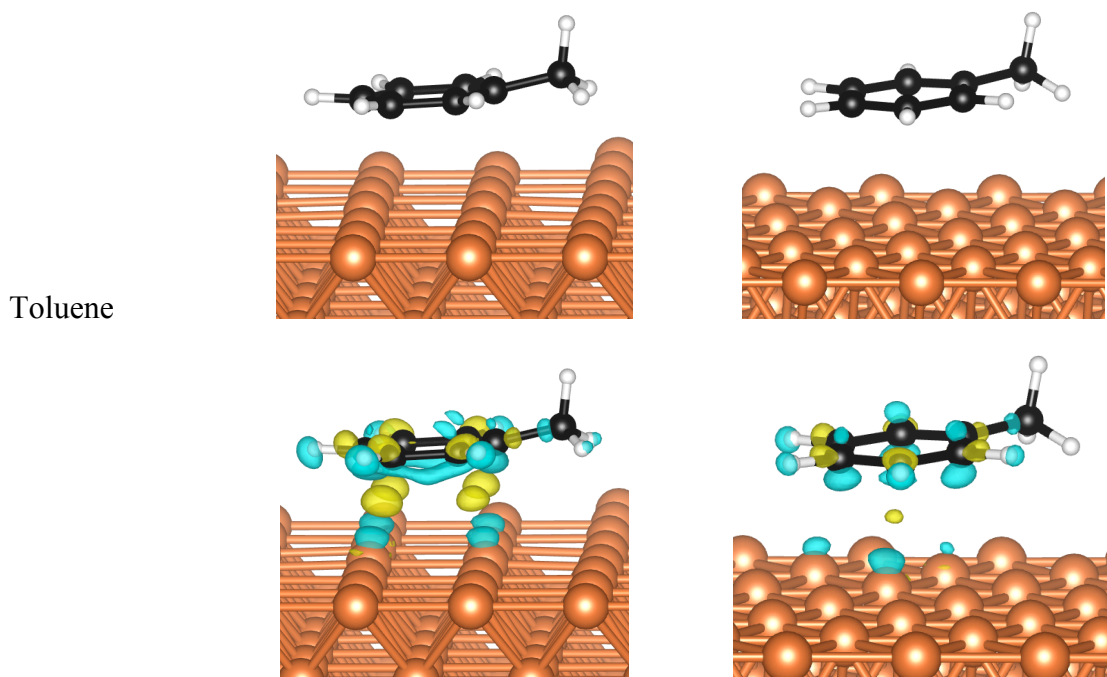


Figure S6. Molecular models for (*E*)- S_{2H} , S_{4H} and toluene adsorbed on the (100) and (111) terminations of *fcc* copper. The bottom images show the charge density differences (see method section). Yellow and blue colors represent accumulation or depletion of charge density, respectively. The values for isosurfaces are $\pm 2.5 \cdot 10^{-3} \text{ e} \cdot \text{\AA}^{-3}$ for all models.

Kinetic data and modelling

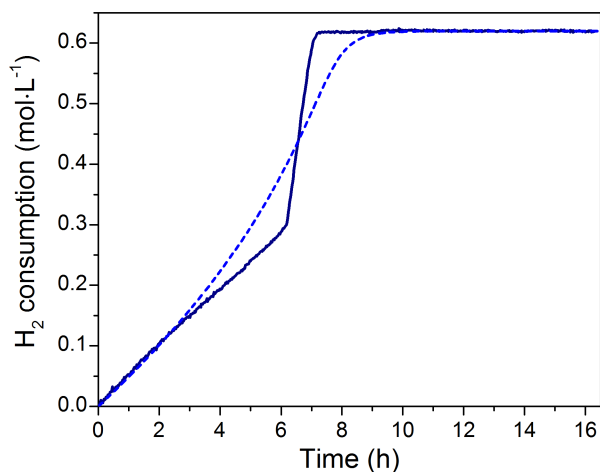
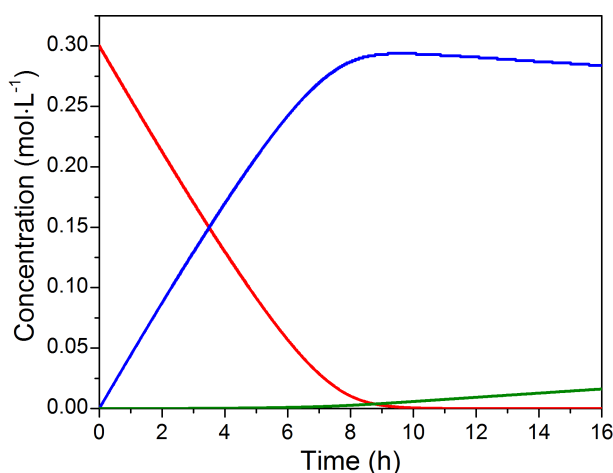


Figure S7. Experimental H_2 consumption profile (solid line) during hydrogenation of **S** at 40 °C on Cu/SiO_2 and the corresponding fit using K adsorption constants measured from adsorption isotherms (dashed line).

120

a)



b)

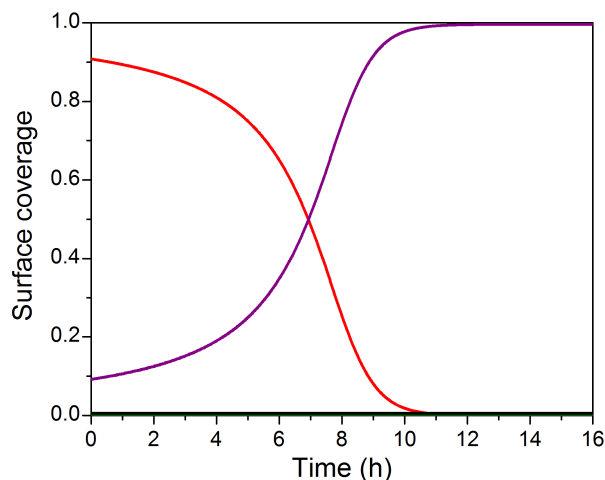


Figure S8. a) Simulated concentrations in **S** (red), $\text{S}_{2\text{H}}$ (blue), $\text{S}_{4\text{H}}$ (green) and b) surface coverage on Cu/SiO_2 in S^* (red), $\text{S}_{2\text{H}}^*$ (blue), $\text{S}_{4\text{H}}^*$ (green), IMes^* (purple) and empty sites * (black) in the presence of IMes in a 1:50 IMes/S ratio.

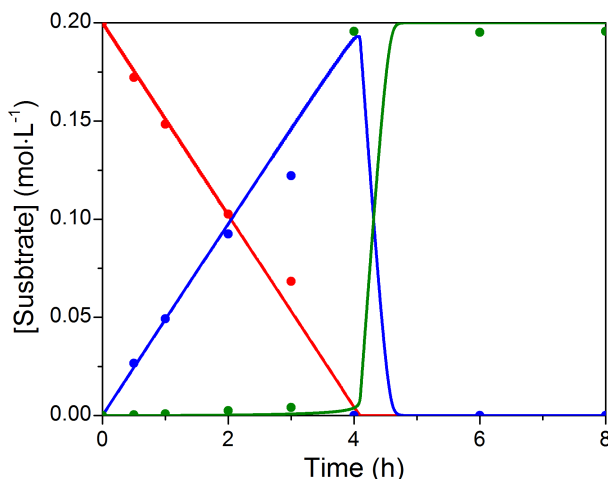
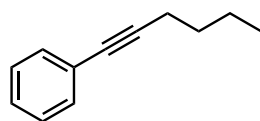


Figure S9. Experimental concentrations S (red), S_{2H} (blue), S_{4H} (green) from GC analysis (dots) during hydrogenation of S at 40 °C, 20 bar H_2 on Cu/SiO_2 (0.375 mol%; sample and data from ref^[4]) and corresponding simulated concentrations using constants from Table 3 (lines).

a)



1-phenyl-1-hexyne

b)

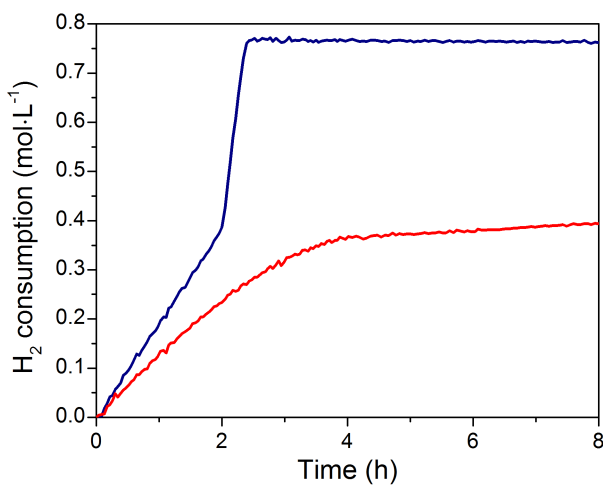


Figure S10. a) Structure of 1-phenyl-1-hexyne and b) H_2 consumption profiles during hydrogenation of 1-phenyl-1-hexyne with Cu/SiO_2 (ca. 0.8 mol% Cu_{total} and 0.3 mol% $Cu_{surface}$ vs 1-phenyl-1-hexyne) at 10 bar H_2 and 40 °C in the absence (blue) or in the presence (red) of PCy_3 in 1:50 PCy_3 /1-phenyl-1-hexyne ratio.

References

- 130 [1] K. Larmier, S. Tada, A. Comas-Vives, C. Coperet, *J. Phys. Chem. Lett.*, 7 (2016) 3259.
[2] L. Červený, V. Růžička, *Cat. Rev.*, 24 (1982) 503.
[3] L. Červený, V. Růžička, *Adv. Catal.*, 30 (1981) 335.
[4] A. Fedorov, H.J. Liu, H.K. Lo, C. Coperet, *J. Am. Chem. Soc.*, 138 (2016) 16502.